

CD54HC154, CD74HC154, CD54HCT154

Data sheet acquired from Harris Semiconductor

September 1997 - Revised June 2004

High-Speed CMOS Logic 4- to 16-Line Decoder/Demultiplexer

Features

- Two Enable Inputs to Facilitate Demultiplexing and Cascading Functions
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

The 'HC154 and 'HCT154 are 4- to 16-line decoders/demultiplexers with two enable inputs, E1 and E2.

A High on either enable input forces the output into the High state. The demultiplexing function is performed by using the four input lines, A0 to A3, to select the output lines $\overline{Y0}$ to $\overline{Y15}$, and using one enable as the data input while holding the other enable low.

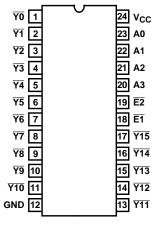
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC154F3A	-55 to 125	24 Ld CERDIP
CD54HCT154F3A	-55 to 125	24 Ld CERDIP
CD74HC154E	-55 to 125	24 Ld PDIP
CD74HC154EN	-55 to 125	24 Ld PDIP
CD74HC154M	-55 to 125	24 Ld SOIC
CD74HC154M96	-55 to 125	24 Ld SOIC
CD74HCT154E	-55 to 125	24 Ld PDIP
CD74HCT154EN	-55 to 125	24 Ld PDIP
CD74HCT154M	-55 to 125	24 Ld SOIC
CD74HCT154M96	-55 to 125	24 Ld SOIC

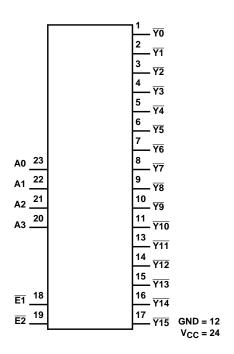
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.

Pinout

CD54HC154, CD54HCT154 (CERDIP) CD74HC154, CD74HCT154 (PDIP, SOIC) TOP VIEW



Functional Diagram



TRUTH TABLE

INPUTS												OUTI	PUTS								
E1	E2	А3	A2	A 1	Α0	<u>Y0</u>	<u>Y1</u>	<u>Y2</u>	<u></u> 73	<u>¥4</u>	<u>Y5</u>	<u>¥6</u>	<u>77</u>	<u>¥8</u>	<u>Y9</u>	<u>Y10</u>	<u>Y11</u>	<u>Y12</u>	<u>Y13</u>	<u>Y14</u>	<u>Y15</u>
L	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
L	L	L	L	L	Н	Н	L	Η	Η	Н	Η	Н	Н	Н	Н	Н	Ι	Η	Н	Η	Н
L	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
L	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
L	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
L	L	L	Н	L	Н	Н	Η	Η	Η	Н	L	Н	Н	Н	Н	Н	Ι	Η	Н	Η	Н
L	L	L	Н	Ι	L	Η	Τ	Ι	Ι	Ι	Ι	L	Н	Η	Η	Н	Ι	Ι	Н	Ι	Н
L	L	L	Н	Ι	Η	Η	Τ	Ι	Ι	Ι	Ι	Н	L	Η	Η	Н	Ι	Τ	Н	Ι	Н
L	L	Ι	L	L	L	Η	Τ	Ι	Ι	Ι	Ι	Н	Н	L	Η	Н	Ι	Τ	Н	Ι	Н
L	L	Ι	L	L	Η	Η	Τ	Ι	Ι	Ι	Ι	Н	Н	Η	L	Н	Ι	Τ	Н	Ι	Н
L	L	Η	L	Η	L	Ι	Ι	Ι	Ι	Η	Ι	Н	Н	Н	Η	L	Ι	Η	Н	Ι	Н
L	L	Η	L	Η	Η	Ι	Ι	Ι	Ι	Η	Ι	Н	Н	Η	Η	Η	L	Η	Н	Ι	Н
L	L	Η	Ι	L	L	Ι	Ι	Ι	Ι	Η	Ι	Н	Н	Н	Η	Η	Ι	L	Н	Ι	Н
L	L	Η	Ι	L	Η	Ι	Ι	Ι	Ι	Η	Ι	Н	Н	Н	Η	Η	Ι	Η	L	Ι	Н
L	L	Η	Ι	Η	L	Ι	Ι	Ι	Ι	Η	Ι	Н	Н	Н	Η	Η	Ι	Η	Н	ا	Н
L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Η	Н	Н	Н	L
L	Н	Χ	Х	Х	Χ	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Η	Н	Н	Н	Н
Н	L	Χ	Х	Х	Χ	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Η	Н	Н	Н	Н
Н	Н	Х	Χ	Х	Χ	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н

H = High Voltage Level, L = Low Voltage Level, X = Don't Care

Thermal Information

Thermal Resistance (Typical)	θ _{JA} (^o C/W)
E (PDIP) Package (.600) (Note 1)	67
EN (PDIP) Package (.300) (Note 1)	67
M (SOIC) Package (Note 2)	46
Maximum Junction Temperature	150°C
Maximum Storage Temperature Range6	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range (T _A)55°C to 125°C
Supply Voltage Range, V _{CC}
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, $V_I, V_O \dots 0V$ to V_{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

- 1. The package thermal impedance is calculated in accordance with JESD 51-3.
- 2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TES CONDI		V _{CC}		25°C		-40°C 1	O 85°C	-55 ⁰ C T		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)			TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	•	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	ı	1.35	-	1.35	-	1.35	V
				6	-	ı	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	ı	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
omeo Edudo			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	1		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
112 20000			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
omeo Edudo			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
TTE LOUGS			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	l _l	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	lcc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ

DC Electrical Specifications (Continued)

	TEST CONDITION			V _{CC}		25°C		-40°C 1	O 85°C	-55°C TO 125°C			
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HCT TYPES						-	-	-	-	-	-		
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V	
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V	
High Level Output Voltage CMOS Loads	Voн	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V	
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V	
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V	
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V	
Input Leakage Current	lį	V _{CC} and GND	0	5.5	-		±0.1	-	±1	-	±1	μΑ	
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μА	
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 3)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ	

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
A0 - A3	1.4
<u>₹1,</u> ₹2	1.3

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., 360µA max at $25^{o}C.$

Switching Specifications Input t_r , $t_f = 6ns$

		TEST		25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	-								-		
Propagation Delay (Figure 1)	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
Address to Output			4.5	-	-	35	-	44	-	53	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns

^{3.} For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

		TEST			25°C		-40 ⁰ 85	С ТО °С	-55°C T	O 125 ⁰ C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
E1 to Output	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
			4.5	-	-	35	=	44	-	53	ns
		C _L =15pF	5	-	14	-	=	-	-	-	ns
		C _L = 50pF	6	-	-	30	=	37	-	45	ns
E2 to Output	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	175	=	220	-	265	ns
			4.5	-	-	35	-	44	-	53	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
(Figure 1)			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C _{IN}	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	-	88	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay (Figure 2) Address to Output	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	35	-	44	-	53	ns
		C _L =15pF	5	-	14	-	-		-	-	ns
E1 to Output	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	34	-	43	-	51	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
E2 to Output	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-		34	-	43	-	51	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C _{IN}	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5		84	-	-	-	-	-	pF

NOTES:

^{4.} $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per gate.

^{5.} $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = input frequency, C_L = output load capacitance, V_{CC} = supply voltage.

Test Circuits and Waveforms

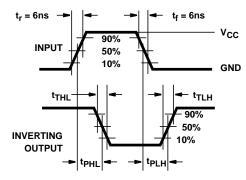


FIGURE 1. HC AND HCU TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

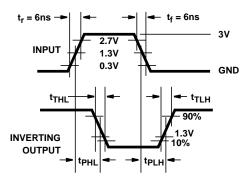


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
5962-8670101JA	Active	Production	CDIP (J) 24	15 TUBE	No	Call TI	N/A for Pkg Type	-55 to 125	5962-8670101JA CD54HCT154F3A
5962-8682201JA	Active	Production	CDIP (J) 24	15 TUBE	No	Call TI	N/A for Pkg Type	-55 to 125	5962-8682201JA CD54HC154F3A
CD54HC154F3A	Active	Production	CDIP (J) 24	15 TUBE	No	Call TI	N/A for Pkg Type	-55 to 125	5962-8682201JA CD54HC154F3A
CD54HC154F3A.A	Active	Production	CDIP (J) 24	15 TUBE	No	Call TI	N/A for Pkg Type	-55 to 125	5962-8682201JA CD54HC154F3A
CD54HCT154F3A	Active	Production	CDIP (J) 24	15 TUBE	No	Call TI	N/A for Pkg Type	-55 to 125	5962-8670101JA CD54HCT154F3A
CD54HCT154F3A.A	Active	Production	CDIP (J) 24	15 TUBE	No	Call TI	N/A for Pkg Type	-55 to 125	5962-8670101JA CD54HCT154F3A
CD74HC154M	Obsolete	Production	SOIC (DW) 24	-	-	Call TI	Call TI	-55 to 125	HC154M
CD74HC154M96	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-55 to 125	HC154M
CD74HC154M96.A	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M
CD74HC154M96E4	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M
CD74HC154M96G4	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M
CD74HC154M96G4.A	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M
CD74HCT154M	Obsolete	Production	SOIC (DW) 24	-	-	Call TI	Call TI	-55 to 125	HCT154M
CD74HCT154M96	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M
CD74HCT154M96.A	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

PACKAGE OPTION ADDENDUM

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(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF CD54HC154, CD54HC1154, CD74HC154, CD74HC1154:

Catalog: CD74HC154, CD74HCT154

Military: CD54HC154, CD54HCT154

NOTE: Qualified Version Definitions:

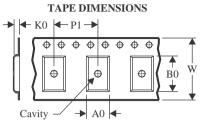
- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC154M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD74HC154M96G4	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD74HCT154M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC154M96	SOIC	DW	24	2000	350.0	350.0	43.0
CD74HC154M96G4	SOIC	DW	24	2000	350.0	350.0	43.0
CD74HCT154M96	SOIC	DW	24	2000	350.0	350.0	43.0

4040084/C 10/97

J (R-GDIP-T**)

24 PINS SHOWN

CERAMIC DUAL-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Window (lens) added to this group of packages (24-, 28-, 32-, 40-pin).
- D. This package can be hermetically sealed with a ceramic lid using glass frit.
- E. Index point is provided on cap for terminal identification.



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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